# **BYW80-200**

# SWITCHMODE<sup>™</sup> Power Rectifiers

This state-of-the-art device is designed for use in switching power supplies, inverters and as free wheeling diodes.

### Features

- Ultrafast 35 Nanosecond Recovery Time
- 175°C Operating Junction Temperature
- Popular TO-220 Package
- Epoxy Meets UL 94 V-0 @ 0.125 in
- Low Forward Voltage
- Low Leakage Current
- High Temperature Glass Passivated Junction
- Pb–Free Package is Available\*

### **Mechanical Characteristics**

- Case: Epoxy, Molded
- Weight: 1.9 Grams (Approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead Temperature for Soldering Purposes: 260°C Max. for 10 Seconds

### MAXIMUM RATINGS

Rating	Symbol Values		Unit	
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	200	V	
Average Rectified Forward Current Total Device, (Rated V <sub>R</sub> ), T <sub>C</sub> = 150°C	I <sub>F(AV)</sub>	8.0	A	
Peak Repetitive Forward Current (Rated V <sub>R</sub> , Square Wave, 20 kHz), $T_{C} = 150^{\circ}C$	I <sub>FM</sub>	16	A	
Nonrepetitive Peak Surge Current (Surge applied at rated load conditions halfwave, single phase, 60 Hz)	I <sub>FSM</sub>	100	A	
Operating Junction Temperature and Storage Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-65 to +175	°C	

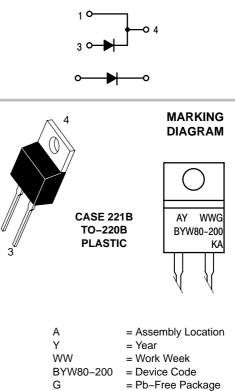
Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.



## **ON Semiconductor®**

http://onsemi.com

## ULTRAFAST RECTIFIERS 8.0 AMPERES, 200 VOLTS



= Diode Polarity

### ORDERING INFORMATION

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Device	Package	Shipping
BYW80-200	TO-220	50 Units/Rail
BYW80-200G	TO–220 (Pb–Free)	50 Units/Rail

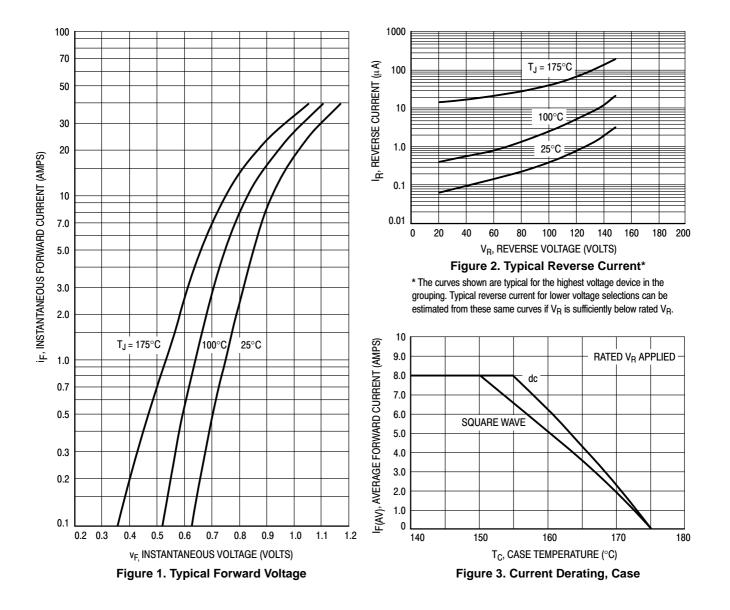
\*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

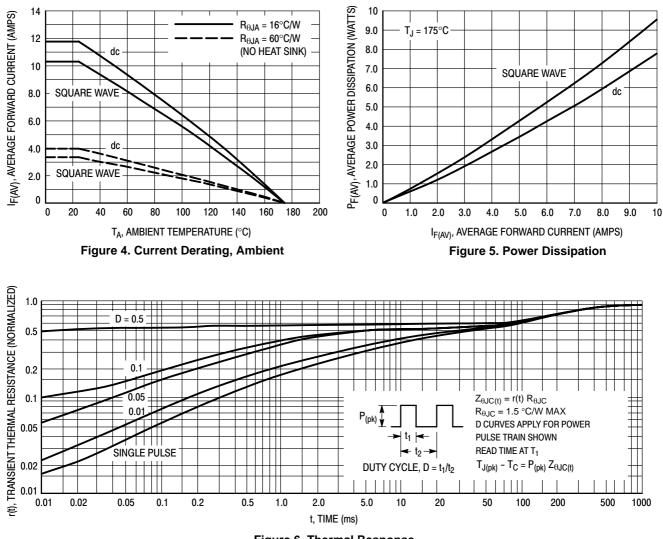
### THERMAL CHARACTERISTICS

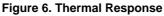
Rating	Symbol	Values	Unit
Maximum Thermal Resistance, Junction-to-Case	$R_{\thetaJC}$	3.0	°C/W
ELECTRICAL CHARACTERISTICS			

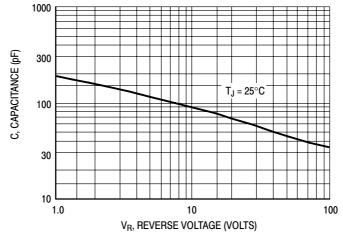
Maximum Instantaneous Forward Voltage (Note 1) ( $i_F = 7.0 \text{ Amps}, T_C = 100^{\circ}\text{C}$ ) ( $i_F = 22 \text{ Amps}, T_C = 25^{\circ}\text{C}$ )	V <sub>F</sub>	0.85 1.25	V
Maximum Instantaneous Reverse Current (Note 1) (Rated dc Voltage, $T_J = 100^{\circ}C$ ) (Rated dc Voltage, $T_J = 25^{\circ}C$ )	i <sub>R</sub>	1 0.01	mA
Maximum Reverse Recovery Time (I <sub>F</sub> = 1.0 Amp, di/dt = 50 Amps/μs) (I <sub>F</sub> = 0.5 Amp, i <sub>R</sub> = 1.0 Amp, I <sub>REC</sub> = 0.25 Amp)	t <sub>rr</sub>	35 25	ns

1. Pulse Test: Pulse Width  $\leq$  300  $\mu$ s, Duty Cycle  $\leq$  2.0%.





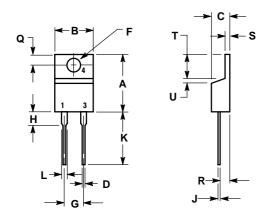






### PACKAGE DIMENSIONS

TO-220 TWO-LEAD CASE 221B-04 ISSUE D



Y14.5M, 1982. CONTROLLING DIMENSION: INCH.				
	INC	HES	MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
Α	0.595	0.620	15.11	15.75
В	0.380	0.405	9.65	10.29
С	0.160	0.190	4.06	4.82
D	0.025	0.035	0.64	0.89
F	0.142	0.147	3.61	3.73
G	0.190	0.210	4.83	5.33
Н	0.110	0.130	2.79	3.30
J	0.018	0.025	0.46	0.64
K	0.500	0.562	12.70	14.27
L	0.045	0.060	1.14	1.52
Q	0.100	0.120	2.54	3.04
R	0.080	0.110	2.04	2.79
S	0.045	0.055	1.14	1.39
Т	0.235	0.255	5.97	6.48
U	0.000	0.050	0.000	1.27

1. DIMENSIONING AND TOLERANCING PER ANSI

NOTES

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